DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

NEW PRODUCT

Features

- Dual P-Channel MOSFET
- Low On-Resistance
  - 5.0Ω @ -4.5V
  - 7.0Ω @ -2.5V
  - 10Ω @ -1.8V
  - 15Ω @ -1.5V
- Very Low Gate Threshold Voltage $V_{GS(TH)}$ <1V
- Low Input Capacitance
- Fast Switching Speed
- **Lead Free By Design/RoHS Compliant (Note 2)**
- **ESD Protected Gate**
- **"Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

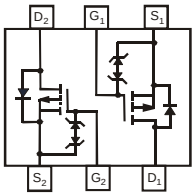
Mechanical Data

- Case: SOT-963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish - Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Weight: 0.0027 grams (approximate)

SOT-963

ESD protected

TOP VIEW



Internal Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V_{DSS}	-20	V
Gate-Source Voltage		V_{GSS}	±8	V
Continuous Drain Current (Note 1)	@T_A = 25°C @T_A = 85°C	I_D	-140 -100	mA
Pulsed Drain Current	T_P = 10µs	I_{DM}	-600	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P_D	330	mW
Thermal Resistance, Junction to Ambient, Note 1	$R_{\theta JA}$	377.16	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
1. Device mounted on 1"x1" FR-4 substrate PC board, with minimum recommended pad layout, single sided.
2. No purposefully added lead.
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

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Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)						
Drain-Source Breakdown Voltage	BV_{DSS}	-20	—	—	V	V_{GS} = 0V, I_D = -250mA
Zero Gate Voltage Drain Current	I_{DSS}	— —	— —	-100 -50	nA nA	V_{DS} = -16V, V_{GS} = 0V V_{DS} = -5.0V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±5.0V, V_{DS} = 0V
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage	$V_{GS(th)}$	-0.5	—	-1.0	V	V_{DS} = V_{GS}, I_D = -250µA
Static Drain-Source On-Resistance	$R_{DS\ (ON)}$	—	— — — —	5.0 7.0 10 15	Ω	V_{GS} = -4.5V, I_D = -100mA V_{GS} = -2.5V, I_D = -50mA V_{GS} = -1.8V, I_D = -20mA V_{GS} = -1.5V, I_D = -10mA
Forward Transfer Admittance	$\|Y_{fs}\|$	200	—	—	mS	V_{DS} = -10V, I_D = -0.2A
Diode Forward Voltage (Note 4)	V_{SD}	-0.5	—	-1.2	V	V_{GS} = 0V, I_S = -115mA
DYNAMIC CHARACTERISTICS (Note 5)						
Input Capacitance	C_{iss}	—	13.72	175	pF	V_{DS} = -15V, V_{GS} = 0V f = 1.0MHz
Output Capacitance	C_{oss}	—	4.01	30	pF	
Reverse Transfer Capacitance	C_{rss}	—	2.34	20	pF	
SWITCHING CHARACTERISTICS (Note 5)						
Turn-On Delay Time	$t_{d(on)}$	—	20	—	ms	V_{GS} = -4.5V, V_{DD} = -15V I_D = -180mA, R_G = 2.0Ω
Rise Time	t_r	—	37	—		
Turn-Off Delay Time	$t_{d(off)}$	—	112	—		
Fall Time	t_f	—	97	—		

Notes: 4. Short duration pulse test used to minimize self-heating effect.
5. Guaranteed by design. Not subject to production testing.

Typical Characteristics

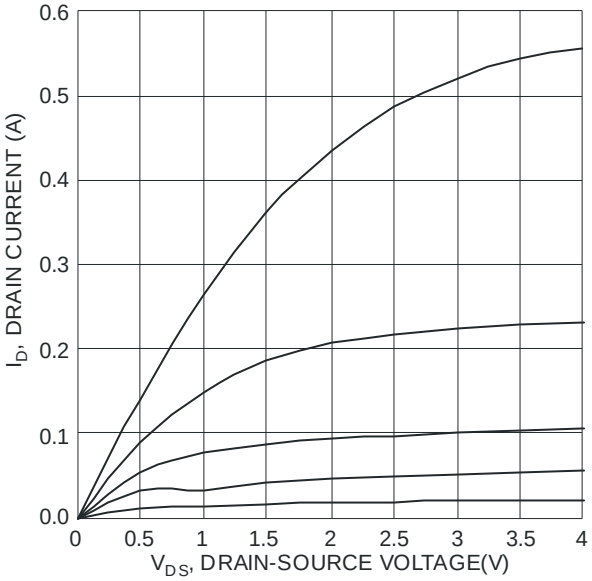

Fig. 1 Typical Output Characteristics

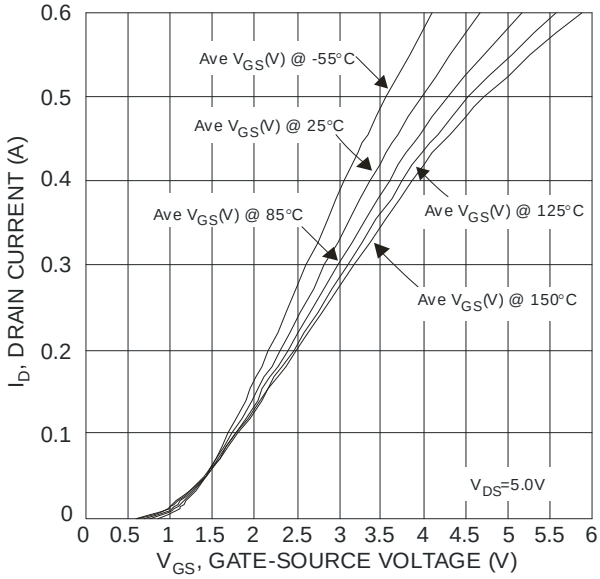

Fig. 2 Typical Transfer Characteristics

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Typical Characteristics

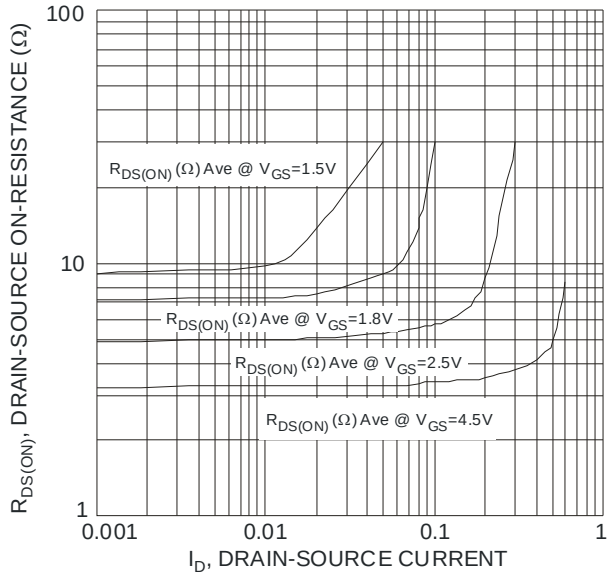

Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

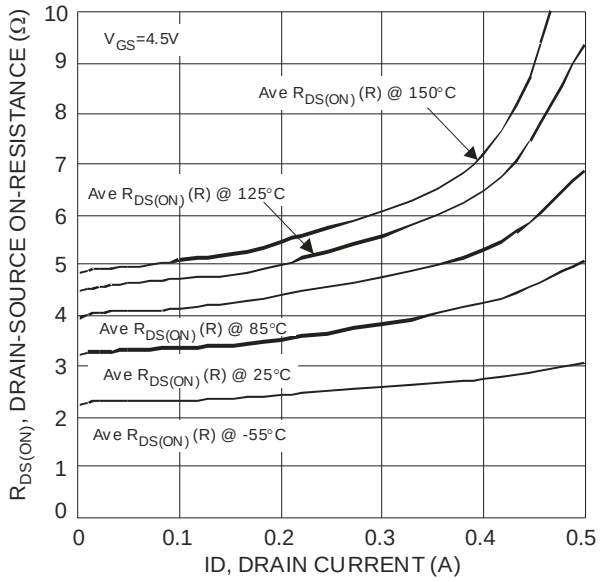

Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

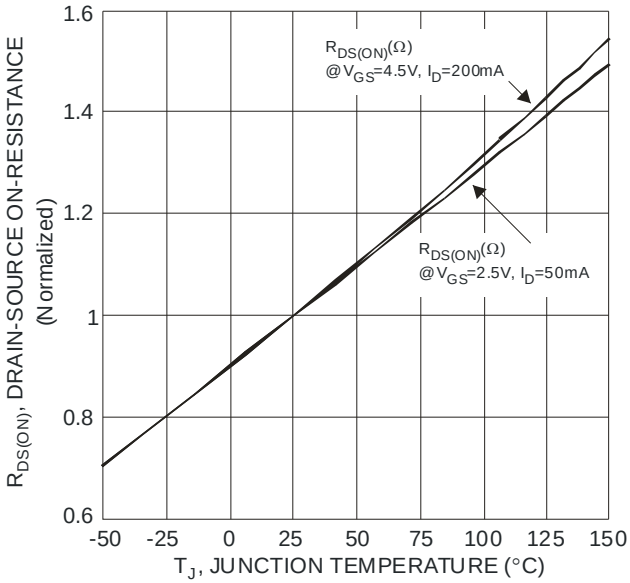

Fig. 5 On-Resisitance Variation with Temperature

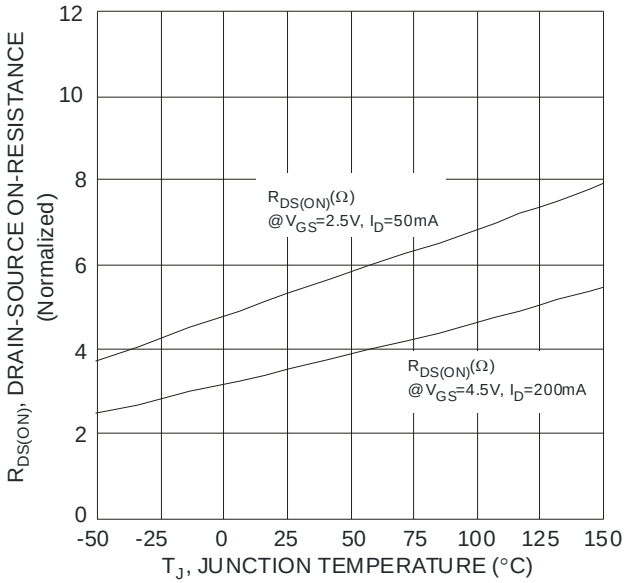

Fig. 6 On-Resisitance vs.Temperature

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Typical Characteristics

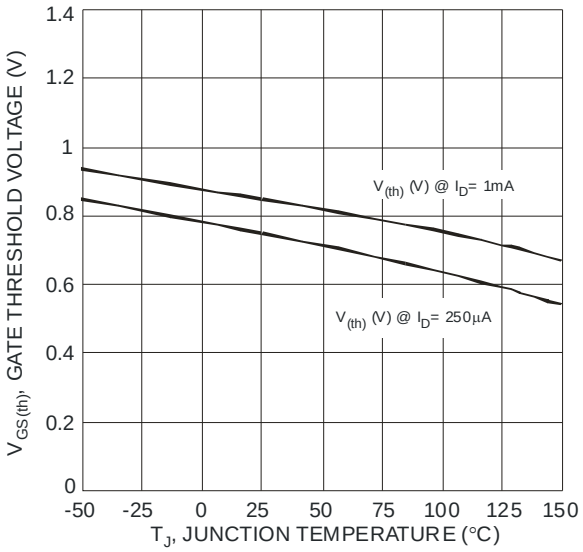

Fig. 7 Gate Threshold Variation vs. Ambient Temperature

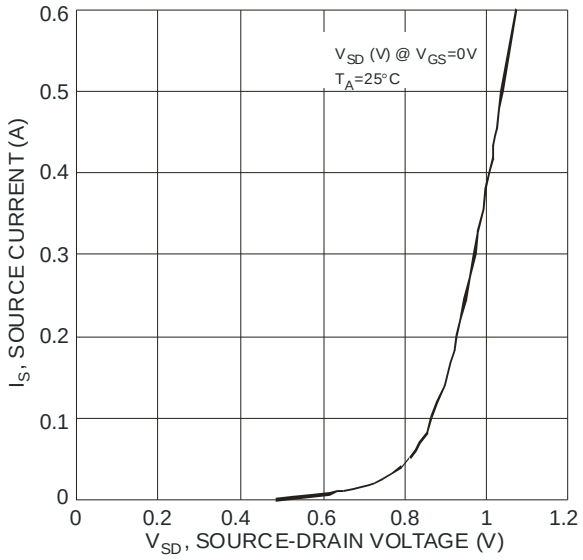

Fig. 8 Diode Forward Voltage vs. Current

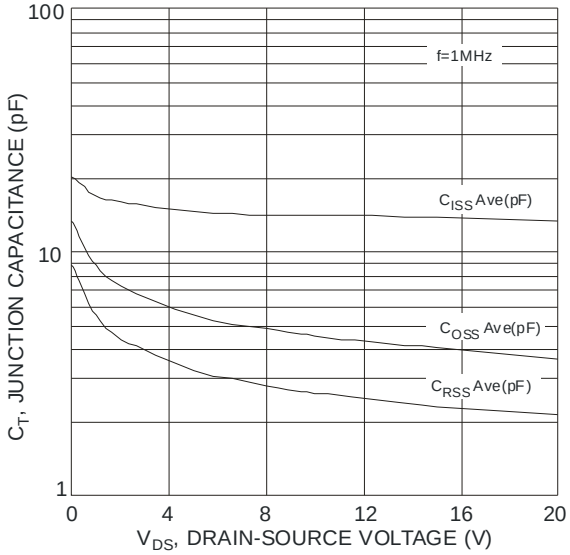

Fig. 9 Typical Junction Capacitance

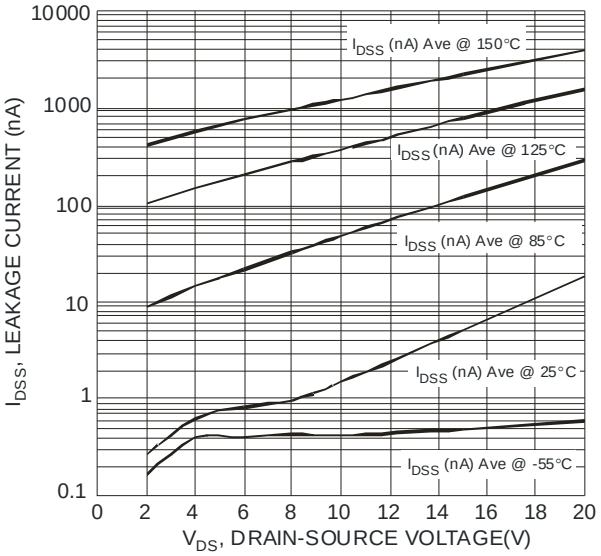

Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

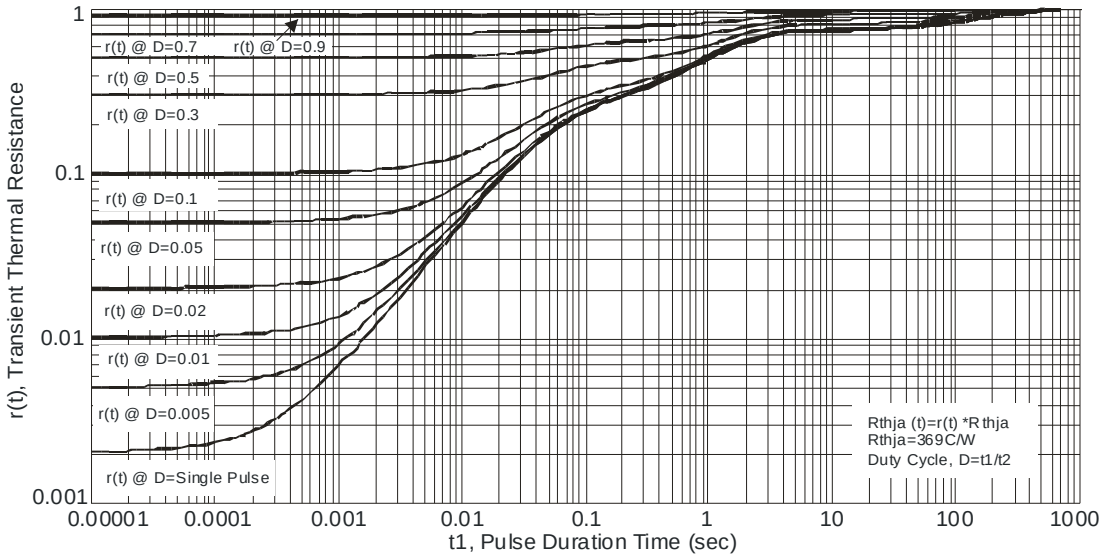

Fig. 11 Transient Thermal Resistance

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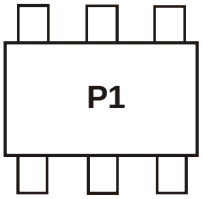
Ordering Information (Note 6)

Part Number	Case	Packaging
DMP210DUDJ-7	SOT-963	10,000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

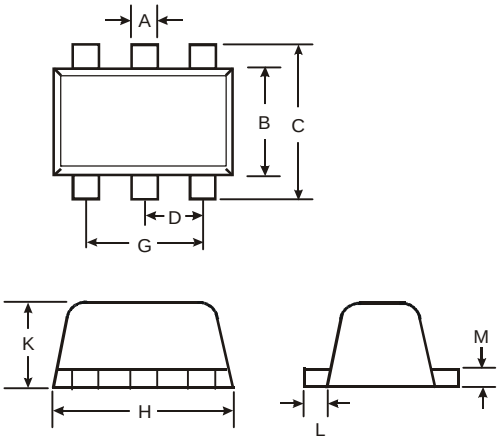
Marking Information (Note 7)



P1 = Product Type Marking Code

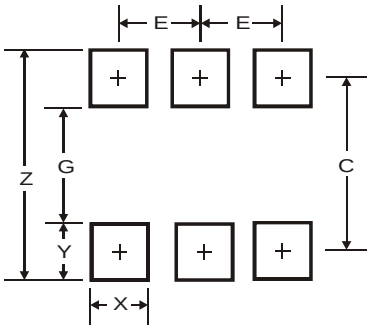
Notes: 7. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Package Outline Dimensions



SOT-963			
Dim	Min	Max	Typ
A	0.10	0.20	0.15
B	0.95	1.05	1.00
C	0.95	1.05	1.00
D		0.35	
G		0.70	
H	0.95	1.05	1.00
K	0.40	0.50	0.45
L	0.05	0.15	0.10
M	0.05	0.15	0.10
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.10
G	0.70
X	0.20
Y	0.20
C	0.90
E	0.35

NEW PRODUCT

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